

## Features

- High reliability
- General purpose leads
- Peak wavelength  $\lambda_p=940\text{nm}$
- Mechanically and spectrally matched to the phototransistor
- Low forward voltage
- High radiant intensity

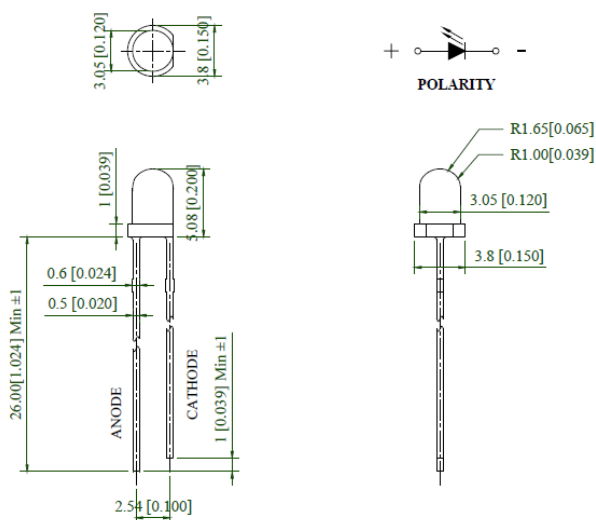
## Applications

- Optoelectronic Switch
- IR Touch-Panel
- Industrial IR Equipment
- Consumer Electronics
- High Speed IR Communications

## Description

- The infrared emitting diode (940nm) is a high intensity diode, molded in a water clear transparent plastic package.
- The device is spectrally matched with silicon photodiode and phototransistor.

## Package Dimensions in mm



### Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is  $\pm 0.25$  mm (.010 ") unless otherwise noted.

**Figure 1. INL-3AHIR30 Package Dimensions**

### Absolute Maximum Rating at 25°C (Note 1)

Product	Emission Color	$P_d$ (mW)	$I_f$ (mA)	$I_{FP}^*$ (A)	$V_R$ (V)	$T_{OP}$ (°C)	$T_{ST}$ (°C)
INL-3AHIR30	Infrared	150	100	1	5	-40°C~+80°C	-40°C~+85°C

#### Notes

1. Condition for  $I_{FP}$  is pulse of 1/10 duty and 1kHz frequency

### Electrical Characteristics $T_A = 25^\circ\text{C}$ (Note 1)

Product	Emission Color	$I_f$ (mA)	$V_F$ (V)		$\lambda$ (nm)			Viewing Angle	$E_e$ (mW/sr)	
			min	max	$\lambda_D$	$\lambda_P$	$\Delta\lambda$	$2\theta_{1/2}$	min	typ.
INL-3AHIR30	Infrared	20	0.8	1.5	-	940	50	30	6	10

#### Notes

1. Performance guaranteed only under conditions listed in above tables.

### ESD Precaution

ATTENTION: Electrostatic Discharge (ESD) protection

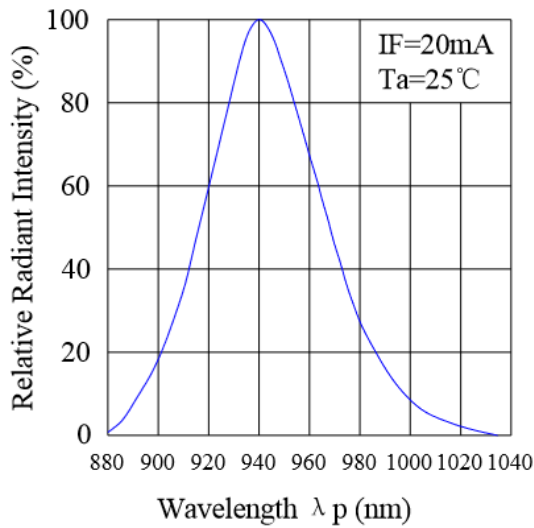


The symbol above denotes that ESD precaution is needed. ESD protection for GaP and AlGaAs based chips is necessary even though they are relatively safe in the presence of low static-electric discharge. Parts built with AlInGaP, GaN, or/and InGaN based chips are STATIC SENSITIVE devices. ESD precaution must be taken during design and assembly. If manual work or processing is needed, please ensure the device is adequately protected from ESD during the process.

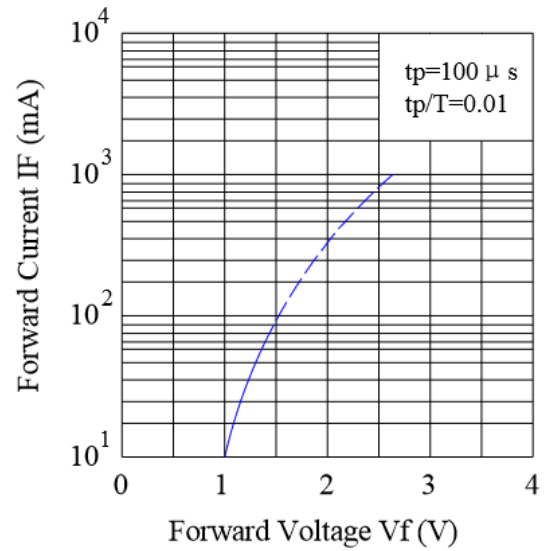
Please be advised that normal static precautions should be taken in the handling and assembly of this device to prevent damage or degradation which may be induced by electrostatic discharge (ESD).

## Typical Characteristic Curves

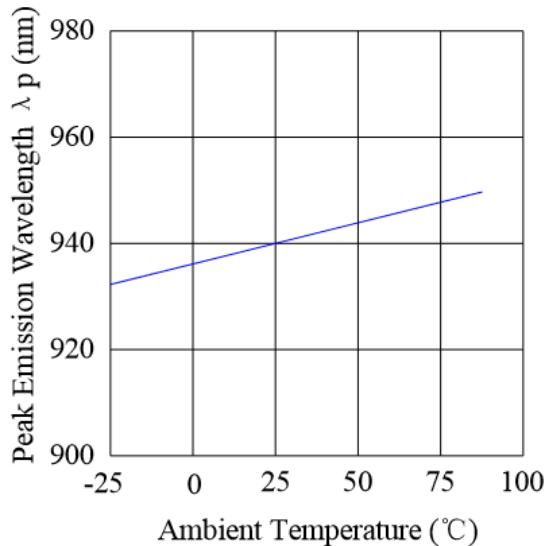
Spectral Distribution



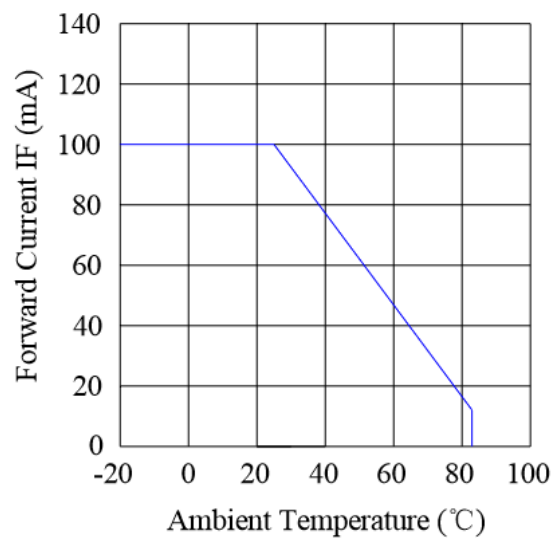
Forward Current & Forward Voltage



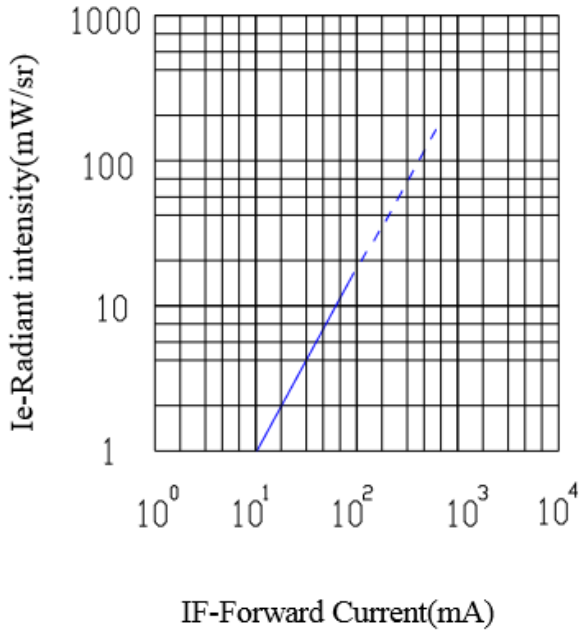
Peak Emission Wavelength & Ambient Temperature



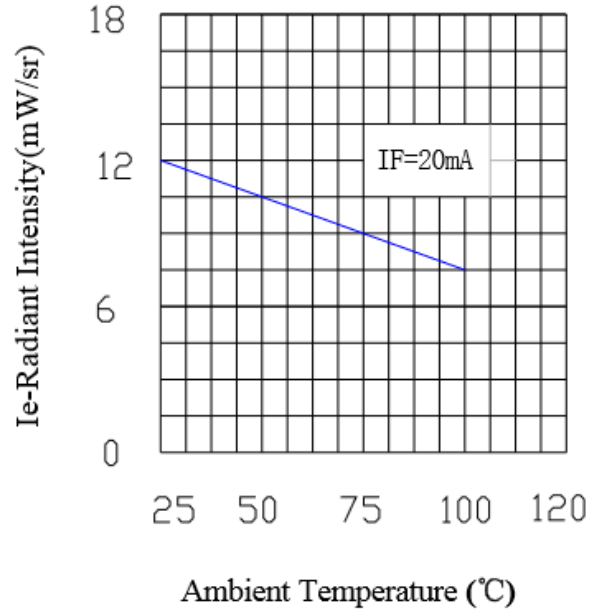
Forward Current & Ambient Temperature



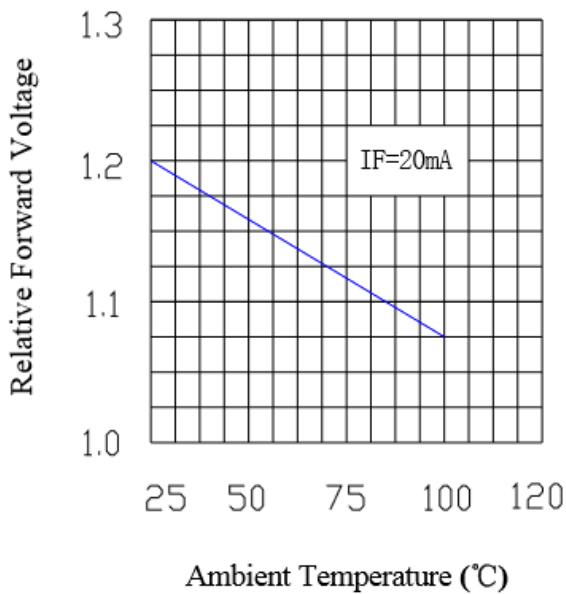
Relative Intensity &  
Forward Current



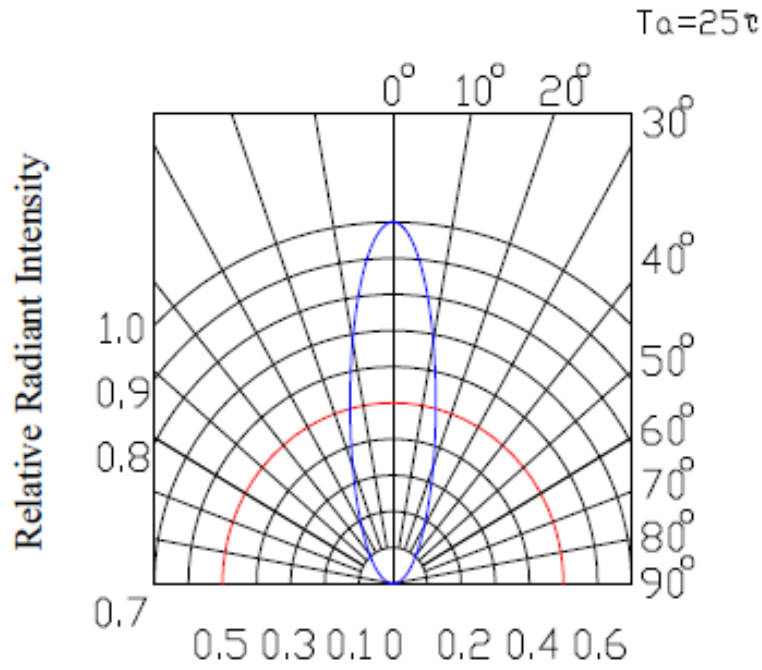
Relative Intensity &  
Ambient Temperature(°C)



Forward Voltage &  
Ambient Temperature(°C)



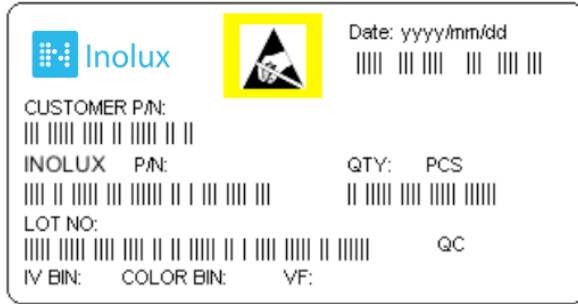
### Typical Characteristic Curves – Radiation Pattern



### Ordering Information

Product	Emission Color	Technology	Test Current $I_F$ (mA)	Radiant Intensity $E_e$ (mW/sr) (Typ.)	Forward Voltage $V_F$ (V) (Typ.)	Orderable Part Number
INL-3AHIR30	Infrared	AlGaAs	20	10	1.2	INL-3AHIR30

**Label Specifications**



**Inolux P/N:**

I	N	L	-	3	A	-	HIR	3	0	.	X	X	X	X
Inolux Lamp Type			Package	Lens	Color	View Angle		Customized Stamp-off						
			3A = standard 3mm	(Blank) = clear	HIR = 940nm	30 = 30 deg.								

**Lot No.:**

Z	2	0	1	7	01	24	001
Internal Tracker	Year (2017, 2018, .....)				Month	Date	Serial

**Reliability**

Item	Frequency/ lots/ samples/ failures	Standards Reference	Conditions
Precondition	For all reliability monitoring tests according to JEDEC Level 2	J-STD-020	1.) Baking at 85°C for 24hrs 2.) Moisture storage at 85°C/ 60% R.H. for 168hrs
Solderability	1Q/ 1/ 22/ 0	JESD22-B102-B And CNS-5068	Accelerated aging 155°C/ 24hrs Tinning speed: 2.5+0.5cm/s Tinning: A: 215°C/ 3+1s or B: 260°C/ 10+1s
Resistance to soldering heat		CNS-5067	Dipping soldering terminal only Soldering bath temperature A: 260+/-5°C; 10+/-1s B: 350+/-10°C; 3+/-0.5s
Operating life test	1Q/ 1/ 40/ 0	CNS-11829	1.) Precondition: 85°C baking for 24hrs 85°C/ 60%R.H. for 168hrs 2.) Tamb25°C; IF=20mA; duration 1000hrs
High humidity, high temperature bias	1Q/ 1/ 45/ 0	JESD-A101-B	Tamb: 85°C Humidity: 85% R.H., IF=5mA Duration: 1000hrs
High temperature bias	1Q/ 1/ 20	IN specs.	Tamb: 55°C IF=20mA Duration: 1000hrs
Pulse life test	1Q/ 1/ 40/ 0		Tamb25°C, If=20mA,, Ip=100mA, Duty cycle=0.125 (tp=125 μs, T=1sec) Duration 500hrs)
Temperature cycle	1Q/ 1/ 76/ 0	JESD-A104-A IEC 68-2-14, Nb	A cycle: -40 degree C 15min; +85 degree C 15min Thermal steady within 5 min.. 300 cycles 2 chamber/ Air-to-air type
High humidity storage test	1Q/ 1/ 40/ 0	CNS-6117	60+3°C 90+5/-10% R.H. for 500hrs
High temperature storage test	1Q/ 1/ 40/ 0	CNS-554	100+10°C for 500hrs
Low temperature storage test	1Q/ 1/ 40/ 0	CNS-6118	-40+5°C for 500hrs

## Revision History

Changes since last revision	Page	Version No.	Revision Date
Initial Release		1.0	01-19-2019

## DISCLAIMER

INOLUX reserves the right to make changes without further notice to any products herein to improve reliability, function or design. INOLUX does not assume any liability arising out of the application or use of any product or circuit described herein; neither does it convey any license under its patent rights, nor the rights of others.

## LIFE SUPPORT POLICY

INOLUX's products are not authorized for use as critical components in life support devices or systems without the express written approval of the President of INOLUX or INOLUX CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Inolux:](#)

[INL-3AHIR30](#)